

HAC RF TESTREPORT

No. I18Z60073-SEM02

For

TCL Communication Ltd.

GSM Quad-band/HSPA-UMTS Six-band/ LTE 19-band mobile phone

Model Name: BBF100-1

With

Hardware Version: 09

Software Version: AAX573

FCC ID: 2ACCJN026

Results Summary: M Category = M4

Issued Date: 2018-5-9



Note:

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Test Laboratory:

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REPORT HISTORY

Report Number	Revision	Issue Date	Description
I18Z60073-SEM02	Rev.0	2018-5-9	Initial creation of test report



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1 Test Laboratory

1.1 Testing Location

CompanyName:	CTTL(Shouxiang)
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,
	Beijing, P. R. China100191

1.2 Testing Environment

Temperature:	18°C~25°C,		
Relative humidity:	30%~ 70%		
Ground system resistance:	< 0.5 Ω		
Ambient poice is checked and found very low and in compliance with requirement of standards			

Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.

1.3 Project Data

Project Leader:	Qi Dianyuan
Test Engineer:	Lin Hao
Testing Start Date:	April 29, 2018
Testing End Date:	April 29, 2018

1.4 Signature

Lin Xiaojun

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

Lu Bingsong

Deputy Director of the laboratory

(Approved this test report)



2 Client Information

2.1 Applicant Information

Company Name	TCL Communication Ltd.			
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Company Address	International E City, Zhong Shan Yuan Road, Nanshan District,			
	Shenzhen, Guangdong, P.R. China 518052			
Post Code	518052			
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E-Mail	zhizhou.gong@tcl.com			
Company URL	www.alcatel-mobile.com			

2.2 Manufacturer Information

Company Name	TCL Communication Ltd.			
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Company Address	International E City, Zhong Shan Yuan Road, Nanshan District,			
	Shenzhen, Guangdong, P.R. China 518052			
Post Code	518052			
Contact Person	Zhizhou Gong			
Tel	0086-755-36611722			
Mobile	0086-18217635320			
Fax	0086-755-36612000 ext: 81722			
E-Mail	zhizhou.gong@tcl.com			
Company URL	www.alcatel-mobile.com			



3 Equipment Under Test (EUT) and Ancillary Equipment (AE)

This EUT is a variant product and the report of original sample is No.I18Z60070-SEM02. According to the client request, we quote the test results of original sample directly. And increase the results of LTE band4/26.Delete the results of LTE band14/30/66.

3.1 About EUT

Description:	GSM Quad-band/HSPA-UMTS Six-band/ LTE 19-band mobile phone
Model name:	BBF100-1
Operating mode(s):	GSM 850/900/1800/1900 WCDMA850/900/1700/1900/2100
	LTE B1/2/3/4/5/7/8/12/13/17/19/20/26/28/32/38/39/40/41, BT, WLAN

3.2 Internal Identification of EUT used during the test

EUT ID*	IMEI	HW Version	SW Version
EUT1	015103000009634	09	4S3L
EUT2	015103000009683	09	4S3L
EUT3	353741090004971	09	AAX573

^{*}EUT ID: is used to identify the test sample in the lab internally.

3.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
AE1	Battery	TLp035B1	1	BYD

^{*}AE ID: is used to identify the test sample in the lab internally.

3.4 Air Interfaces / Bands Indicating Operating Modes

Air-interface	Band(MHz)	Туре	C63.19/tested	Simultaneous Transmissions	ОТТ
GSM	850	VO	Yes		
GSIVI	1900	VO		BT, WLAN	NΙΛ
GPRS/EDGE	850	DT	NA	DI, WLAIN	NA
GPR3/EDGE	1900	וט	INA		
	850		Yes	BT, WLAN	NA
WCDMA	1700	VO			
(UMTS)	1900				
	HSPA	DT	NA		
LTE	Band 2/4/5/7/12/13/26/41	V/D	Yes	BT, WLAN	NA
ВТ	2450	DT	NA	GSM, WCDMA, LTE	NA
WLAN	2450	V/D	Yes	GSM, WCDMA, LTE	NA
WLAN	5G	V/D	Yes	GSM, WCDMA, LTE	NA

VO: Voice CMRS/PSTN Service Only V/D: Voice CMRS/PSTN and Data Service DT: Digital Transport

^{*} HAC Rating was not based on concurrent voice and data modes, Non current mode was found to represent worst case rating for both M and T rating



4 CONDUCTED OUTPUT POWER MEASUREMENT

4.1 Summary

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured output power should be greater and within 5% than EMI measurement.

4.2 Conducted Power

GSM		Conducted Power (dBm)			
850MHz	Channel 251(848.8MHz)	Channel 190(836.6MHz)	Channel 128(824.2MHz)		
OSUMINZ	32.69	32.44	32.69		
GSM		Conducted Power(dBm)			
1900MHz	Channel 810(1909.8MHz)	Channel 661(1880MHz)	Channel 512(1850.2MHz)		
1900141112	30.40	30.30	30.26		
WCDMA		Conducted Power (dBm)			
850MHz	Channel 4233(846.6MHz)	Channel 4182(836.4MHz)	Channel 4132(826.4MHz)		
030141112	23.68	23.56	23.58		
WCDMA		Conducted Power (dBm)			
1700MHz	Channel 1513 (1752.6MHz)	Channel 1412 (1732.4MHz)	Channel 1312 (1712.4MHz)		
1700WIFIZ	23.39	23.41	23.55		
WCDMA	Conducted Power (dBm)				
1900MHz	Channel 9538(1907.6MHz)	Channel 9400(1880MHz)	Channel 9262(1852.4MHz)		
1900141112	23.47	23.70	23.74		
LTE		Conducted Power (dBm)			
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)		
QPSK	23.32	23.53	23.32		
LTE		Conducted Power (dBm)			
Band5	Channel 20600(844MHz)	Channel 20525(836.5MHz)	Channel20450(829MHz)		
QPSK	23.16	23.14	23.12		
LTE		Conducted Power (dBm)			
Band7	Channel 21350(2560MHz)	Channel21100(2535MHz)	Channel 20850(2510MHz)		
QPSK	22.97	23.03	23.05		
LTE		Conducted Power (dBm)			
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)		
QPSK	23.00	22.97	23.02		
LTE	Conducted Power (dBm)				
Band13	Channel 23230(782MHz)				
QPSK	23.21				
LTE		Conducted Power (dBm)			



Band41	Channel	Channel		Channel		hannel	Channel
QPSK	41490(2680MH	41055(263	6.5M	40620(2593MH	40185(2549.5M		39750(2506MH
	z)	Hz)		z)		Hz)	z)
	22.96	23.03		23.06		23.09	23.08
LTE			Cor	nducted Power (dl	Bm)		
Band2	Channel 19100		Cha	annel18900(1880N	/IHz)	Channel 1	18700(1860MHz)
16-QAM	22.79			22.82			22.88
LTE			Cor	nducted Power (dl	Bm)		
Band5	Channel 20600((844MHz)	Char	nnel 20525(836.5M	1Hz)	Channel	20450(829MHz)
16-QAM	22.16			22.00			22.47
LTE			Cor	nducted Power (dl	Bm)		
Band7	Channel 21350	(2560MHz)	Cha	annel21100(2535N	/IHz)	Channel 2	20850(2510MHz)
16-QAM	22.50			22.57			22.69
LTE		Conducted Power (dBm)					
Band12	Channel 23130	(711MHz)	Cha	Channel 23095(707.5MHz) Channel 23060(704			23060(704MHz)
16-QAM	22.16	}		22.07			22.49
LTE			Cor	nducted Power (dl	Bm)		
Band13			Cha	annel 23230(782M	Hz)		
16-QAM				22.26			
			Cor	nducted Power (dl	Bm)		
LTE	Channel	Channe	el	Channel	С	hannel	Channel
Band41	41490(2680MH	41055(263	6.5M	40620(2593MH	4018	5(2549.5M	39750(2506MH
16-QAM	z)	Hz)		z)		Hz)	z)
	22.14	22.41	22.41 22.42 22.31		22.45		
2.4GHz		Conducted Power (dBm)					
802.11b	Channel 11 (24	2462MHz) Channel 6 (2437MHz) Channel 1 (2412MHz			el 1 (2412MHz)		
1M	22.74	74 22.65 22.26					
5GHz	Conducted Power (dBm)						
802.11a	Channel 157 (5785MHz)						
18M				18.29			

LTE	Conducted Power (dBm)				
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)		
64-QAM	21.32	21.44	21.48		
LTE		Conducted Power (dBm)			
Band5	Channel 20600(844MHz)	Channel 20525(836.5MHz)	Channel20450(829MHz)		
64-QAM	21.37	21.40	21.36		
LTE		Conducted Power (dBm)			
Band7	Channel 21350(2560MHz)	Channel21100(2535MHz)	Channel 20850(2510MHz)		
64-QAM	21.25	21.21	20.82		
LTE	Conducted Power (dBm)				
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)		
64-QAM	21.42	21.38	21.31		



LTE		Conducted Power (dBm)					
Band13		Cha	annel 23230(782M	Hz)			
64-QAM			21.21				
		Conducted Power (dBm)					
LTE	Channel	Channel Channel Channel Channel					
Band41	41490(2680MH	41490(2680MH 41055(2636.5M 40620(2593MH 40185(2549.5M 39750(2506MH					
64-QAM	z)	Hz)	z)	Hz)	z)		
	21.12	21.08	21.03	20.91	20.49		

LTE		Conducted Power (dBm)			
Band4	Channel 20300(1745MHz)	Channel 20175(1732.5MHz)	Channel20050(1720MHz)		
QPSK	22.96	22.91	23.10		
LTE		Conducted Power (dBm)			
Band4	Channel 20300(1745MHz)	Channel 20175(1732.5MHz)	Channel20050(1720MHz)		
16-QAM	22.20	22.49	22.54		
LTE		Conducted Power (dBm)			
Band4	Channel 20300(1745MHz)	Channel 20175(1732.5MHz)	Channel20050(1720MHz)		
64-QAM	22.34	22.32	22.23		
LTE		Conducted Power (dBm)			
Band26	Channel 26965(841.5MHz)	Channel 26865(831.5MHz)	Channel26775(822.5MHz)		
QPSK	23.03	23.15	23.18		
LTE		Conducted Power (dBm)			
Band26	Channel 26965(841.5MHz)	Channel 26865(831.5MHz)	Channel26775(822.5MHz)		
16-QAM	22.45	22.08	22.50		
LTE	Conducted Power (dBm)				
Band26	Channel 26965(841.5MHz)	Channel 26865(831.5MHz)	Channel26775(822.5MHz)		
64-QAM	21.39	21.37	21.38		



5 Reference Documents

5.1 Reference Documents for testing

The following document listed in this section is referred for testing.

Reference	Title	Version	
ANSI C63.19-2011	American National Standard for Methods of Measurement of	2011	
	Compatibility between Wireless Communication Devices and	Edition	
	Hearing Aids		
FCC 47 CFR §20.19	Hearing Aid Compatible Mobile Headsets	2015	
		Edition	
KDB 285076 D01	Equipment Authorization Guidance for Hearing Aid Compatibility	v04	



6 OPERATIONAL CONDITIONS DURING TEST

6.1 HAC MEASUREMENT SET-UP

These measurements are performed using the DASY5 NEO automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. A cell controller system contains the power supply, robot controller, teach pendant (Joystick),and remote control, is used to drive the robot motors. The PC consists of the HP Intel Core21.86 GHz computer with Windows XP system and HAC Measurement Software DASY5 NEO, A/D interface card, monitor, mouse, and keyboard. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE)circuit performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

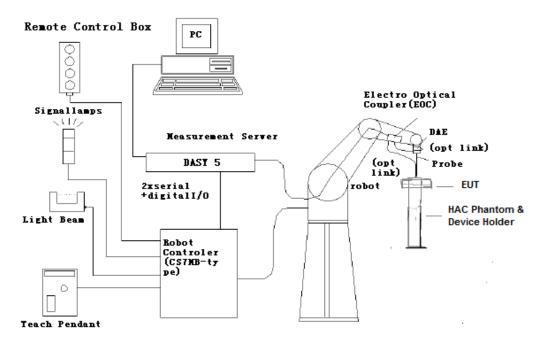


Fig. 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



6.2 Probe Specification

E-Field Probe Description

Construction One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%,

k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity ± 0.2 dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements

Fast automatic scanning in phantoms



[ER3DV6]



6.3Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: $370 \times 370 \times 370 \text{ mm}$).

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field $<\pm 0.5$ dB.

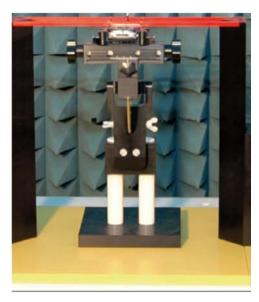


Fig. 2 HAC Phantom & Device Holder

6.4Robotic System Specifications

Specifications

Positioner: Stäubli Unimation Corp. Robot Model: RX160L

Repeatability: ±0.02 mm

No. of Axis: 6

Data Acquisition Electronic (DAE) System

Cell Controller

Processor: Intel Core2 Clock Speed: 1.86GHz

Operating System: Windows XP

Data Converter

Features: Signal Amplifier, multiplexer, A/D converter, and control logic

Software: DASY5 software

Connecting Lines: Optical downlink for data and status info.

Optical uplink for commands and clock



7 EUT ARRANGEMENT

7.1 WD RF Emission Measurements Reference and Plane

Figure 4 illustrates the references and reference plane that shall be used in the WD emissions measurement.

- The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.
- The grid is centered on the audio frequency output transducer of the WD (speaker or T-coil).
- The grid is located by reference to a reference plane. This reference plane is the planar area that contains the highest point in the area of the WD that normally rests against the user's ear
- The measurement plane is located parallel to the reference plane and 15 mm from it, out from the phone. The grid is located in the measurement plane.

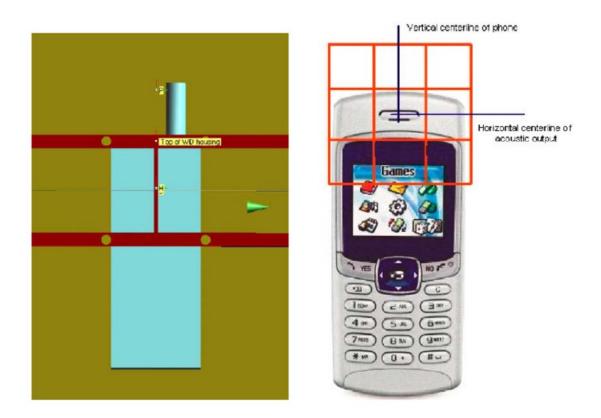


Fig. 3 WD reference and plane for RF emission measurements



8 SYSTEM VALIDATION

8.1 Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical output. Position the E-field probes so that:

- •The probes and their cables are parallel to the coaxial feed of the dipole antenna
- •The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions
- The center point of the probe element(s) are 15 mm from the closest surface of the dipole elements.

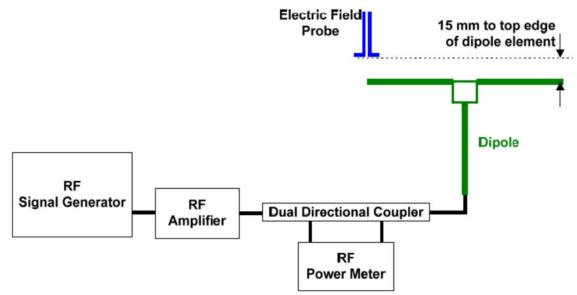


Fig. 4 Dipole Validation Setup

8.2 Validation Result

	E-Field Scan						
Mode	le Frequency Input Power Measured ¹ Target ² Deviation ³ Limit ⁴						
	(MHz)	(mW)	Value(dBV/m)	Value(dBV/m)	(%)	(%)	
CW	835	100	40.53	40.67	-1.60	±25	
CW	1880	100	39.45	39.24	2.45	±25	
CW	2600	100	38.69	38.74	-0.57	±25	

Notes:

- 1. Please refer to the attachment for detailed measurement data and plot.
- 2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
- 3. Deviation (%) = 100 * (Measured value minus Target value) divided by Target value.
- 4. ANSI C63.19 requires values within \pm 25% are acceptable, of which 12% is deviation and 13% is measurement uncertainty. Values independently validated for the dipole actually used in the measurements should be used, when available.



9 Evaluation of MIF

9.1 Introduction

The MIF (Modulation Interference Factor) is used to classify E-field emission to determine Hearing Aid Compatibility (HAC). It scales the power-averaged signal to the RF audio interference level and is characteristic to a modulation scheme. The HAC standard preferred "indirect" measurement method is based on average field measurement with separate scaling by the MIF. With an Audio Interference Analyzer (AIA) designed by SPEAG specifically for the MIF measurement, these values have been verified by practical measurements on an RF signal modulated with each of the waveforms. The resulting deviations from the simulated values are within the requirements of the HAC standard.

The AIA (Audio Interference Analyzer) is an USB powered electronic sensor to evaluate signals in the frequency range 698MHz - 6 GHz. It contains RMS detector and audio frequency circuits for sampling of the RF envelope.

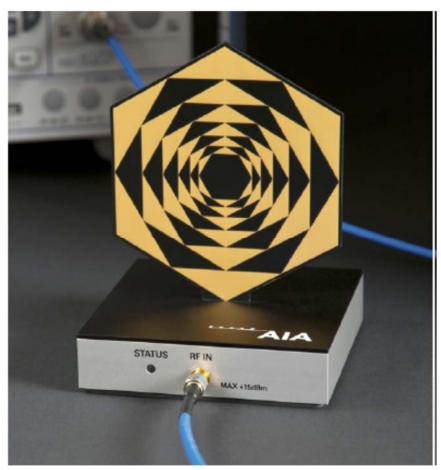


Fig. 5 AIA Front View



9.2 MIF measurement with the AIA

The MIF is measured with the AIA as follows:

- 1. Connect the AIA via USB to the DASY5 PC and verify the configuration settings.
- 2. Couple the RF signal to be evaluated to an AIA via cable or antenna.
- 3. Generate a MIF measurement job for the unknown signal and select the measurement port and timing settings.
- 4. Document the results via the post processor in a report.

9.3 Test equipment for the MIF measurement

No.	Name	Type	Serial Number	Manufacturer
01	Signal Generator	E4438C	MY49071430	Agilent
02	AIA	SE UMS 170 CB	1029	SPEAG
03	BTS	E5515C	MY50263375	Agilent

9.4 Test signal validation

The signal generator (E4438C) is used to generate a 1GHz signal with different modulation in the below table based on the ANSI C63.19-2011. The measured MIF with AIA are compared with the target values given in ANSI C63.19-2011 table D.3, D.4 and D5.

Pulse modulation	Target MIF	Measured MIF	Deviation
0.5ms pulse, 1000Hz repetition rate	-0.9 dB	-0.9 dB	0 dB
1ms pulse, 100Hz repetition rate	+3.9 dB	+3.7 dB	0.2 dB
0.1ms pulse, 100Hz repetition rate	+10.1 dB	+10.0 dB	0.1 dB
10ms pulse, 10Hz repetition rate	+1.6 dB	+1.7 dB	0.1 dB
Sine-wave modulation	Target MIF	Measured MIF	Deviation
1 kHz, 80% AM	-1.2 dB	-1.3 dB	0.1 dB
1 kHz, 10% AM	-9.1 dB	-9.0 dB	0.1 dB
1 kHz, 1% AM	-19.1 dB	-18.9 dB	0.2 dB
100 Hz, 10% AM	-16.1 dB	-16.0 dB	0.1 dB
10 kHz, 10% AM	-21.5 dB	-21.6 dB	0.1 dB
Transmission protocol	Target MIF	Measured MIF	Deviation
GSM; full-rate version 2; speech codec/handset low	+3.5 dB	+3.47 dB	0.03 dB
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB	-19.8 dB	0.2 dB
CDMA; speech; SO3; RC3; full frame rate; 8kEVRC	-19.0 dB	-19.1 dB	0.1 dB
CDMA; speech; SO3; RC1; 1/8 th frame rate; 8kEVRC	+3.3 dB	+3.44 dB	0.14 dB



9.5 DUT MIF results

Typical MIF levels in ANSI C63.19-2011				
Transmission protocol	Modulation interference factor			
GSM; full-rate version 2; speech codec/handset low	+3.5 dB			
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, QPSK)	-15.63 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-9.76 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, 64QAM)	-9.93 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, QPSK)	-1.62 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-1.44 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, 64QAM)	-1.54 dB			

Measured MIF levels				
Band	Channel	Modulation interference factor (dB)		
	251	3.49		
GSM 850	190	3.5		
	128	3.52		
	810	3.51		
GSM 1900	661	3.49		
	512	3.51		
	4233	-23.23		
WCDMA 850	4182	-23.69		
	4132	-23.02		
	1513	-24.04		
WCDMA 1700	1412	-24.32		
	1312	-23.46		
	9538	-23.88		
WCDMA 1900	9400	-24.54		
	9262	-23.42		
LTE Danido	19100	-14.71		
LTE Band2 - QPSK -	18900	-14.16		
QFSK	18700	-14.34		
LTC Dands	20600	-14.48		
LTE Band5 - QPSK -	20525	-14.22		
QFSK	20450	-14.2		
LTC DanidZ	21350	-14.18		
LTE Band7	21100	-14.53		
QFSK	20850	-14.7		
LTE Dond10	23130	-14.63		
LTE Band12 QPSK	23095	-14.59		
QFSK	23060	-14.98		
LTE Band13 QPSK	23230	-14.75		
	41490	-1.78		
LTE Band41	41055	-1.76		
QPSK	40620	-1.68		
	40185	-1.71		



	20750	1.00
	39750	-1.69
LTE Band2	19100	-10.75
16QAM	18900	-10.6
	18700	-9.99
LTE Band5	20600	-10.28
16QAM	20525	-11.07
	20450	-11.04
LTE Band7	21350	-10.5
16QAM	21100	-9.78
100/11/1	20850	-10.5
LTE Band12	23130	-10.08
16QAM	23095	-11.02
IOQAW	23060	-9.73
LTE Band13 16QAM	23230	-9.92
	41490	-1.73
LTC D 144	41055	-1.59
LTE Band41	40620	-1.57
16QAM	40185	-1.67
	39750	-1.50
1.77 5 10	19100	-10.35
LTE Band2	18900	-10.11
64QAM	18700	-9.67
	20600	-10.68
LTE Band5	20525	-10.88
64QAM	20450	-10.32
	21350	-10.72
LTE Band7	21100	-10.25
64QAM	20850	-10.05
	23130	-10.21
LTE Band12	23095	-10.66
64QAM	23060	-9.87
LTE Band13 64QAM	23230	-10.12
	41490	-1.64
<u> </u>	41055	-1.53
LTE Band41	40620	-1.49
64QAM	40185	-1.46
	39750	-1.56
2.4GHz	11	-8.98
802.11b	6	-5.99
5.5M	<u></u> _1	
	I	-9.60
5GHz 802.11a	157	0.47
802.11a 18M	157	-9.17
IOW		

Dand4	20300	-14.58
Band4 QPSK	20175	-14.30
	20050	-14.77





Band26	26965	-14.77
QPSK	26865	-14.50
QFSN	26775	-14.76
Band4	20300	-10.72
16-QAM	20175	-10.06
10-QAW	20050	-10.66
Band26	26965	-10.32
16-QAM	26865	-10.19
TO-QAW	26775	-9.71
Band4	20300	-9.87
64-QAM	20175	-9.54
04-QAW	20050	-9.64
Dand26	26965	-9.46
Band26	26865	-9.87
64-QAM	26775	-9.28



10 Evaluation for low-power exemption

10.1 Product testing threshold

There are two methods for exempting an RF air interface technology from testing. The first method requires evaluation of the MIF for the worst-case operating mode. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is \leq 17 dBm for any of its operating modes. The second method does not require determination of the MIF. The RF emissions testing exemption shall be applied to an RF air interface technology in a device whose peak antenna input power, averaged over intervals \leq 50 μ s20, is \leq 23 dBm. An RF air interface technology that is exempted from testing by either method shall be rated as M4. The first method is used to be exempt from testing for the RF air interface technology in this report.

10.2 Conducted power

Band	Average power (dBm)	MIF (dB)	Sum (dBm)
GSM 850	32.69	3.49	36.18
GSM 1900	30.40	3.51	33.91
WCDMA 850	23.68	-23.23	0.45
WCDMA 1700	23.55	-23.46	0.09
WCDMA 1900	23.74	-23.42	0.32
LTE B2	23.53	-14.16	9.37
LTE B5	23.16	-14.48	8.68
LTE B7	23.05	-14.70	8.35
LTE B12	23.02	-14.98	8.04
LTE B13	23.21	-14.75	8.46
LTE B41	23.09	-1.71	21.38
WiFi-2.4G	22.74	-8.98	13.76
WiFi-5G	18.29	-9.17	9.12
LTE B4	23.10	-14.30	8.8
LTE B26	23.18	-10.06	13.12

10.3 Conclusion

According to the above table, the sums of average power and MIF for UMTS, LTE and WiFi are less than 17dBm. So it is only measured for GSM bands. The UMTS, LTE and WiFi are exempt from testing and rated as M4.



11 RF TEST PROCEDUERES

The evaluation was performed with the following procedure:

- 1) Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2) Position the WD in its intended test position. The gauge block can simplify this positioning.
- 3) Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4) The center sub-grid shall centered on the center of the T-Coil mode axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5) Record the reading.
- 6) Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7) Identify the five contiguous sub-grids around the center sub-grid whose maximum reading is the lowest of all available choices. This eliminates the three sub-grids with the maximum readings. Thus, the six areas to be used to determine the WD's highest emissions are identified.
- 8) Identify the maximum field reading within the non-excluded sub-grids identified in Step 7)
- 9) Evaluate the MIF and add to the maximum steady-state rms field-strength reading to obtain the RF audio interference level..
- Compare this RF audio interference level with the categories and record the resulting WD category rating.



12 Measurement Results (E-Field)

Fre	quency	AWF	Measured Value	Power Drift	Category	MIF
MHz	Channel		(V/m)	(dB)	M?	
	-	•		GSM 850		
	251	0	34.69	-0.02	M4	3.49
	190	0	33.45	-0.03	M4	3.5
	128	0	35.52	0.03	M4	3.52
				PCS 1900		
	810	0	26.73	-0.06	M4	3.51
	661	0	26.47	-0.04	M4	3.49
	512	0	25.99	-0.12	M4	3.51
	•	•	LT	E Band41 QPSK		
	41490	0	21.01	-0.02	M4	-1.78
	41055	0	20.83	-0.10	М4	-1.76
	40620	0	21.10	-0.05	М4	-1.68
	40185	0	20.54	0.07	M4	-1.71
	39750	0	20.14	0.13	M4	-1.69
			LTE	Band41 16-QAM		
	41490	0	20.78	0.05	M4	-1.73
	41055	0	20.66	0.02	M4	-1.59
	40620	0	20.90	-0.15	M4	-1.57
	40185	0	21.05	0.17	M4	-1.67
	39750	0	20.35	0.08	M4	-1.50
	_		LTE	Band41 64-QAM		
	41490	0	21.09	0.11	M4	-1.64
	41055	0	20.93	-0.08	M4	-1.53
	40620	0	20.84	0.04	M4	-1.49
	40185	0	21.20	-0.11	M4	-1.46
	39750	0	20.97	-0.02	M4	-1.56



13 ANSIC 63.19-2011 LIMITS

WD RF audio interference level categories in logarithmic units

Emission categories	< 960 MHz			
	E-field emissions			
Category M1	50 to 55	dB (V/m)		
Category M2	45 to 50	dB (V/m)		
Category M3	40 to 45	dB (V/m)		
Category M4	< 40	dB (V/m)		
Emission categories	>96	0 MHz		
	E-field e	emissions		
Category M1	40 to 45	dB (V/m)		
Category M2	35 to 40	dB (V/m)		
Category M3	30 to 35	dB (V/m)		
Category M4	< 30	dB (V/m)		



14 MEASUREMENT UNCERTAINTY

No.	Error source	Туре	Uncertainty Value(%)	Prob. Dist.	k	c _i E	Standard Uncertainty (%) u (%)E	Degree of freedom V _{eff} or <i>v</i> i
Meas	Measurement System							
1	Probe Calibration	В	5.	N	1	1	5.1	8
2	Axial Isotropy	В	4.7	R	$\sqrt{3}$	1	2.7	∞
3	Sensor Displacement	В	16.5	R	$\sqrt{3}$	1	9.5	∞
4	Boundary Effects	В	2.4	R	$\sqrt{3}$	1	1.4	∞
5	Linearity	В	4.7	R	$\sqrt{3}$	1	2.7	∞
6	Scaling to Peak Envelope Power	В	2.0	R	$\sqrt{3}$	1	1.2	∞
7	System Detection Limit	В	1.0	R	$\sqrt{3}$	1	0.6	∞
8	Readout Electronics	В	0.3	N	1	1	0.3	∞
9	Response Time	В	0.8	R	$\sqrt{3}$	1	0.5	∞
10	Integration Time	В	2.6	R	$\sqrt{3}$	1	1.5	∞
11	RF Ambient Conditions	В	3.0	R	$\sqrt{3}$	1	1.7	∞
12	RF Reflections	В	12.0	R	$\sqrt{3}$	1	6.9	∞
13	Probe Positioner	В	1.2	R	$\sqrt{3}$	1	0.7	∞
14	Probe Positioning	Α	4.7	R	$\sqrt{3}$	1	2.7	∞
15	Extra. And Interpolation	В	1.0	R	$\sqrt{3}$	1	0.6	∞
Test	Test Sample Related							
16	Device Positioning Vertical	В	4.7	R	$\sqrt{3}$	1	2.7	8
17	Device Positioning Lateral	В	1.0	R	$\sqrt{3}$	1	0.6	∞
18	Device Holder and Phantom	В	2.4	R	$\sqrt{3}$	1	1.4	∞
19	Power Drift	В	5.0	R	$\sqrt{3}$	1	2.9	∞



20	AIA measurement	В	12	R	$\sqrt{3}$	1	6.9	∞
Pha	Phantom and Setup related							
21	Phantom Thickness	В	2.4	R	$\sqrt{3}$	1	1.4	∞
Com	Combined standard uncertainty(%) 16.2							
· -	nded uncertainty idence interval of 95 %)	ı	$u_e = 2u_c$	Ν	k=:	2	32.4	

15 MAIN TEST INSTRUMENTS

Table 1: List of Main Instruments

	Table 1. List of Main instruments						
No.	Name	Туре	Serial Number	Calibration Date	Valid Period		
01	Signal Generator	E4438C	MY49071430	January 2, 2018	One Year		
02	Power meter	NRVD	102083	Nevember 01, 2017	One week		
03	Power sensor	NRV-Z5	100542	November 01, 2017	One year		
04	Amplifier	60S1G4	0331848	No Calibration Re	quested		
05	AIA	SE UMS 170 CB	1029	No Calibration Requested			
06	E-Field Probe	ER3DV6	2272	December 19, 2017	One year		
07	DAE	SPEAG DAE4	777	September 8, 2017	One year		
08	HAC Dipole	CD835V3	1023	August 23, 2017	One year		
09	HAC Dipole	CD1880V3	1018	August 23, 2017	One year		
10	HAC Dipole	CD2600V3	1005	March 14, 2018	One year		
11	BTS	E5515C	MY50263375	January 23, 2018	One year		
12	BTS	CMW 500	164049	September 12, 2017	One year		

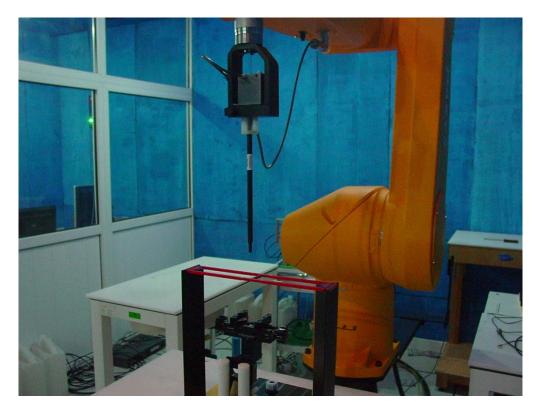
16 CONCLUSION

The HAC measurement indicates that the EUT complies with the HAC limits of the ANSIC63.19-2011. The total M-rating is **M4.**

END OF REPORT BODY



ANNEX A TEST LAYOUT



Picture A1:HAC RF System Layout



ANNEX B TEST PLOTS

HAC RF E-Field GSM 850 High

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

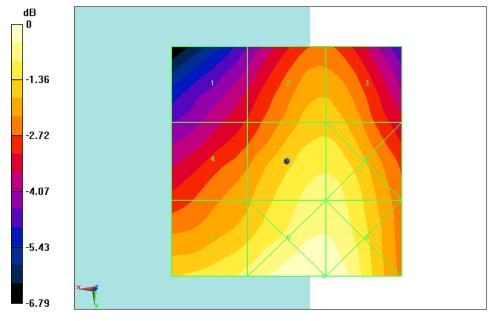
Reference Value = 41.61 V/m; Power Drift = -0.02 dB

Applied MIF = 3.49 dB

RF audio interference level = 34.69 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
32.27 dBV/m	33.83 dBV/m	33.81 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
33.46 dBV/m	34.69 dBV/m	34.69 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
34.61 dBV/m	35.35 dBV/m	35.34 dBV/m



0 dB = 58.53 V/m = 35.35 dBV/m

Fig B.1 HAC RF E-Field GSM 850 High



HAC RF E-Field GSM 850 Middle

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

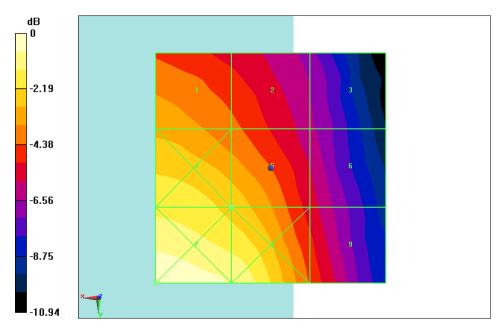
Reference Value = 31.34 V/m; Power Drift = -0.03 dB

Applied MIF = 3.50 dB

RF audio interference level = 33.45 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
32.83 dBV/m	31.78 dBV/m	29.58 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
34.27 dBV/m	33.45 dBV/m	30.49 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
35.9 dBV/m	35.12 dBV/m	31.48 dBV/m



0 dB = 62.34 V/m = 35.90 dBV/m

Fig B.2 HAC RF E-Field GSM 850 Middle



HAC RF E-Field GSM 850 Low

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

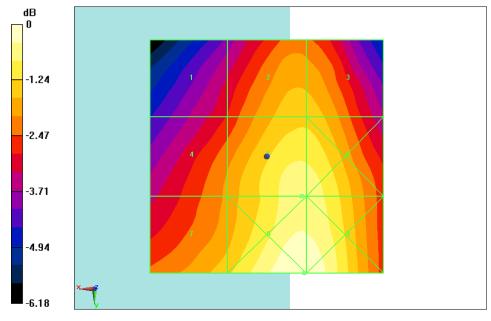
Reference Value = 45.99 V/m; Power Drift = 0.03 dB

Applied MIF = 3.52 dB

RF audio interference level = 35.52 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
33.25 dBV/m	34.74 dBV/m	34.72 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
34.14 dBV/m	35.52 dBV/m	35.5 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
34.77 dBV/m	36.08 dBV/m	36.07 dBV/m



0 dB = 63.68 V/m = 36.08 dBV/m

Fig B.3 HAC RF E-Field GSM 850 Low



HAC RF E-Field GSM 1900 High

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

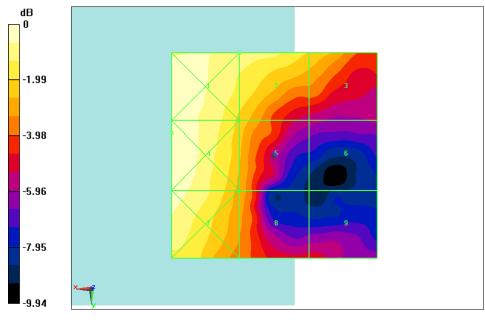
Reference Value = 9.741 V/m; Power Drift = -0.06 dB

Applied MIF = 3.51 dB

RF audio interference level = 26.73 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.61 dBV/m	26.73 dBV/m	25.62 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
27.69 dBV/m	25.52 dBV/m	22.07 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
27.3 dBV/m	24.79 dBV/m	22.82 dBV/m



0 dB = 24.24 V/m = 27.69 dBV/m

Fig B.4 HAC RF E-Field GSM 1900 High



HAC RF E-Field GSM 1900 Middle

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

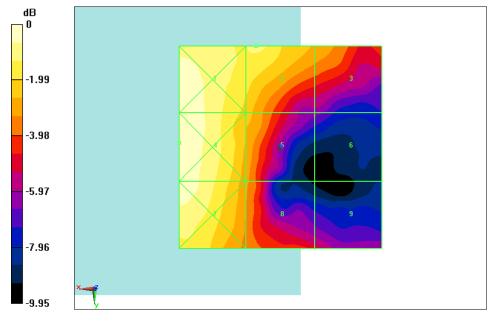
Reference Value = 9.644 V/m; Power Drift = -0.04 dB

Applied MIF = 3.49 dB

RF audio interference level = 26.47 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.44 dBV/m	26.47 dBV/m	24.84 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
27.59 dBV/m	25.31 dBV/m	21.3 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
27.25 dBV/m	24.49 dBV/m	22.66 dBV/m



0 dB = 23.97 V/m = 27.59 dBV/m

Fig B.5 HAC RF E-Field GSM 1900 Middle



HAC RF E-Field GSM 1900 Low

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

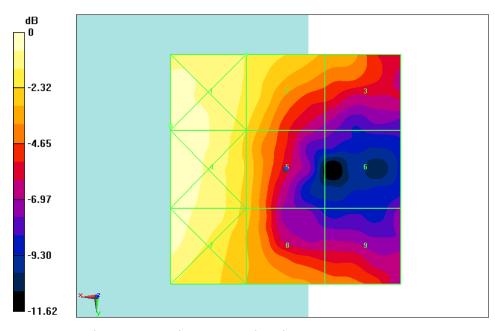
Reference Value = 8.963 V/m; Power Drift = -0.12 dB

Applied MIF = 3.51 dB

RF audio interference level = 25.99 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.57 dBV/m	25.99 dBV/m	24.3 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
27.55 dBV/m	25.26 dBV/m	20.26 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
27.32 dBV/m	24.82 dBV/m	23.36 dBV/m



0 dB = 23.91 V/m = 27.57 dBV/m

Fig B.6 HAC RF E-Field GSM 1900 Low



HAC RF E-Field LTE Band41 QPSK High

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2680 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

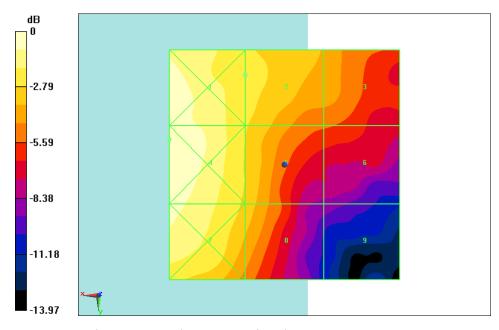
Reference Value = 10.72 V/m; Power Drift = -0.02 dB

Applied MIF = -1.78 dB

RF audio interference level = 21.01 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
23.25 dBV/m	21.01 dBV/m	19.46 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
23.3 dBV/m	20.6 dBV/m	17.9 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
22.76 dBV/m	20.25 dBV/m	14.68 dBV/m



0 dB = 14.63 V/m = 23.30 dBV/m

Fig B.7 HAC RF E-Field LTE Band41 QPSK High



HAC RF E-Field LTE Band41 QPSK 2636.5MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2636.5 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

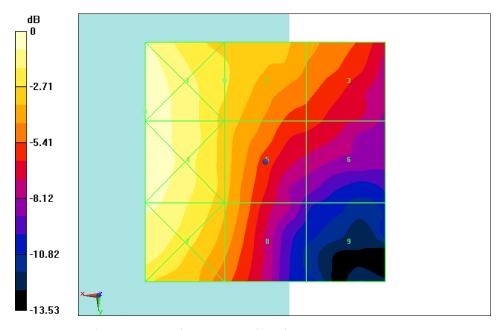
Reference Value = 10.40 V/m; Power Drift = -0.10 dB

Applied MIF = -1.76 dB

RF audio interference level = 20.83 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
23.42 dBV/m	20.83 dBV/m	19.36 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
23.38 dBV/m	20.42 dBV/m	17.52 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
22.67 dBV/m	20.02 dBV/m	14.08 dBV/m



0 dB = 14.82 V/m = 23.42 dBV/m

Fig B.8 HAC RF E-Field LTE Band41 QPSK 2636.5MHz



HAC RF E-Field LTE Band41 QPSK Middle

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2593 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

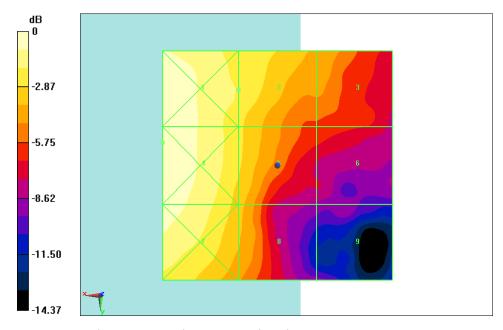
Reference Value = 10.91 V/m; Power Drift = -0.05 dB

Applied MIF = -1.68 dB

RF audio interference level = 21.20 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
23.17 dBV/m	21.2 dBV/m	19.32 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
23.2 dBV/m	20.62 dBV/m	17.26 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
22.63 dBV/m	19.85 dBV/m	14.47 dBV/m



0 dB = 14.46 V/m = 23.20 dBV/m

Fig B.9 HAC RF E-Field LTE Band41 QPSK Middle



HAC RF E-Field LTE Band41 QPSK 2549.5MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2549.5 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

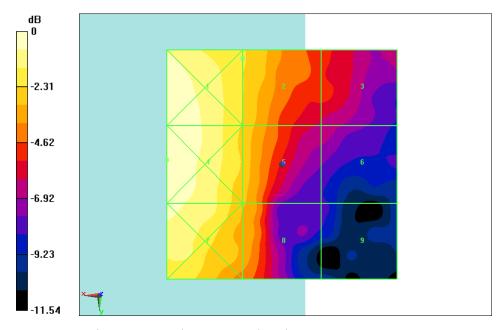
Reference Value = 9.910 V/m; Power Drift = 0.07 dB

Applied MIF = -1.71 dB

RF audio interference level = 20.54 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
22.76 dBV/m	20.54 dBV/m	17.76 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
22.78 dBV/m	20.37 dBV/m	16.49 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
22.32 dBV/m	19.82 dBV/m	14.66 dBV/m



0 dB = 13.77 V/m = 22.78 dBV/m

Fig B.10 HAC RF E-Field LTE Band41 QPSK 2549.5MHz



HAC RF E-Field LTE Band41 QPSK Low

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2506 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

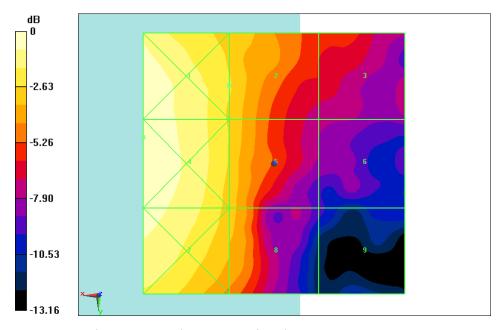
Reference Value = 9.290 V/m; Power Drift = 0.13 dB

Applied MIF = -1.69 dB

RF audio interference level = 20.14 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
22.5 dBV/m	20.14 dBV/m	16.89 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
22.65 dBV/m	19.95 dBV/m	15.19 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
22.11 dBV/m	19.56 dBV/m	13.36 dBV/m



0 dB = 13.56 V/m = 22.65 dBV/m

Fig B.11 HAC RF E-Field LTE Band41 QPSK Low



HAC RF E-Field LTE Band41 16QAM High

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2680 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

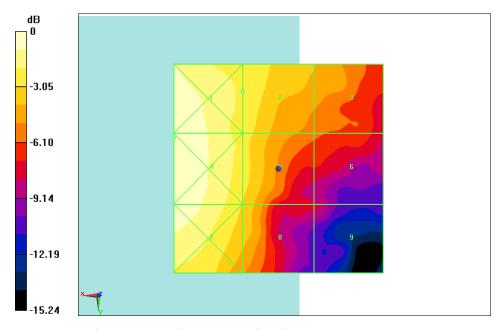
Reference Value = 10.14 V/m; Power Drift = 0.25 dB

Applied MIF = -1.73 dB

RF audio interference level = 20.78 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
23.03 dBV/m	20.78 dBV/m	19.02 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
23.03 dBV/m	20.53 dBV/m	17.28 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
22.65 dBV/m	19.93 dBV/m	15.05 dBV/m



0 dB = 14.17 V/m = 23.03 dBV/m

Fig B.12 HAC RF E-Field LTE Band41 16QAM High



HAC RF E-Field LTE Band41 16QAM 2636.5MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2636.5 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

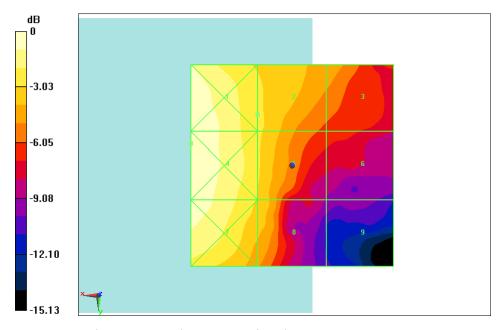
Reference Value = 10.49 V/m; Power Drift = 0.02 dB

Applied MIF = -1.59 dB

RF audio interference level = 20.66 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
23.46 dBV/m	20.66 dBV/m	19.19 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
23.47 dBV/m	20.65 dBV/m	17.12 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
23 dBV/m	20.35 dBV/m	14.25 dBV/m



0 dB = 14.92 V/m = 23.48 dBV/m

Fig B.13 HAC RF E-Field LTE Band41 16QAM 2636.5MHz



HAC RF E-Field LTE Band41 16QAM Middle

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2593 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

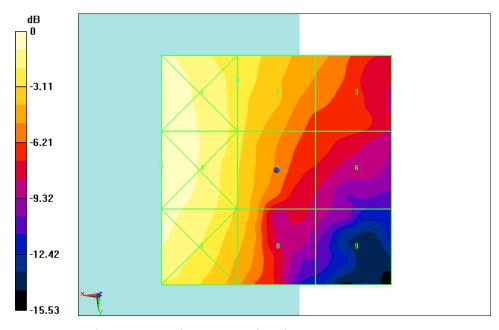
Reference Value = 10.34 V/m; Power Drift = -0.15 dB

Applied MIF = -1.57 dB

RF audio interference level = 20.90 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
23.29 dBV/m	20.9 dBV/m	18.62 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
23.32 dBV/m	20.74 dBV/m	16.71 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
22.77 dBV/m	20.07 dBV/m	14.77 dBV/m



0 dB = 14.66 V/m = 23.32 dBV/m

Fig B.14 HAC RF E-Field LTE Band41 16QAM Middle



HAC RF E-Field LTE Band41 16QAM 2549.5MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2549.5 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

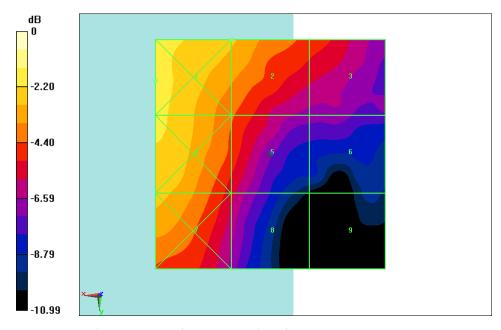
Reference Value = 10.22 V/m; Power Drift = 0.17 dB

Applied MIF = -1.67 dB

RF audio interference level = 21.05 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
22.12 dBV/m	21.05 dBV/m	19.21 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
21.88 dBV/m	19.53 dBV/m	16.92 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
21.16 dBV/m	18.24 dBV/m	14.56 dBV/m



0 dB = 15.49 V/m = 23.80 dBV/m

Fig B.15 HAC RF E-Field LTE Band41 16QAM 2549.5MHz



HAC RF E-Field LTE Band41 16QAM Low

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2506 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

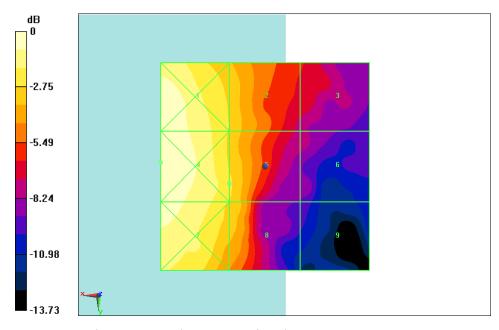
Reference Value = 9.406 V/m; Power Drift = 0.08 dB

Applied MIF = -1.50 dB

RF audio interference level = 20.35 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
22.82 dBV/m	20.11 dBV/m	16.66 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
22.9 dBV/m	20.35 dBV/m	15.16 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
22.61 dBV/m	20.11 dBV/m	13.66 dBV/m



0 dB = 13.97 V/m = 22.90 dBV/m

Fig B.16 HAC RF E-Field LTE Band41 16QAM Low



HAC RF E-Field LTE Band41 64QAM High

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2680 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

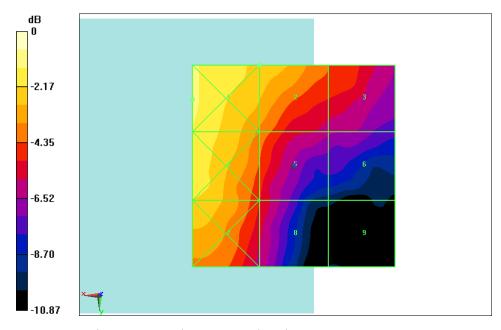
Reference Value = 10.11 V/m; Power Drift = 0.11 dB

Applied MIF = -1.64 dB

RF audio interference level = 21.09 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
22.21 dBV/m	21.09 dBV/m	19.16 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
22.02 dBV/m	19.73 dBV/m	17.21 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
21.29 dBV/m	18.5 dBV/m	13.72 dBV/m



0 dB = 14.93 V/m = 23.48 dBV/m

Fig B.17 HAC RF E-Field LTE Band41 64QAM High



HAC RF E-Field LTE Band41 64QAM 2636.5MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2636.5 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

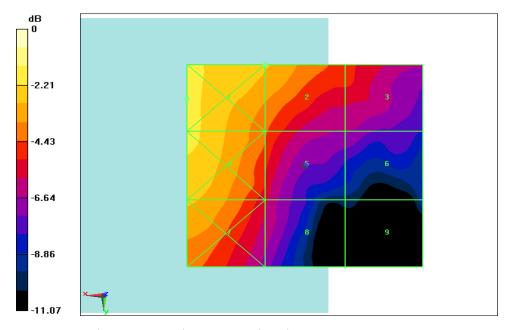
Reference Value = 10.70 V/m; Power Drift = -0.08 dB

Applied MIF = -1.53 dB

RF audio interference level = 20.93 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
22.1 dBV/m	20.93 dBV/m	18.95 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
21.85 dBV/m	19.51 dBV/m	17.22 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
21.01 dBV/m	18.15 dBV/m	14.9 dBV/m



0 dB = 15.50 V/m = 23.81 dBV/m

Fig B.18 HAC RF E-Field LTE Band41 64QAM 2636.5MHz



HAC RF E-Field LTE Band41 64QAM Middle

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2593 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

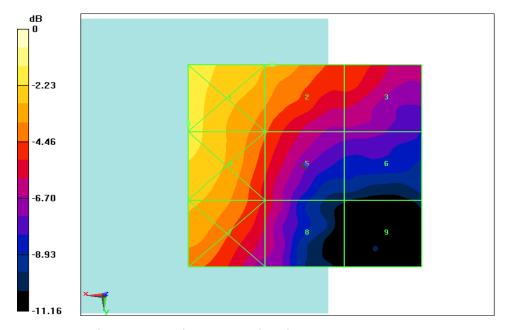
Reference Value = 10.28 V/m; Power Drift = 0.04 dB

Applied MIF = -1.49 dB

RF audio interference level = 20.84 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
22.02 dBV/m	20.84 dBV/m	18.99 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
21.96 dBV/m	19.42 dBV/m	16.87 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
20.99 dBV/m	18.3 dBV/m	13.89 dBV/m



0 dB = 15.39 V/m = 23.74 dBV/m

Fig B.19 HAC RF E-Field LTE Band41 64QAM Middle



HAC RF E-Field LTE Band41 64QAM 2549.5MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2549.5 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

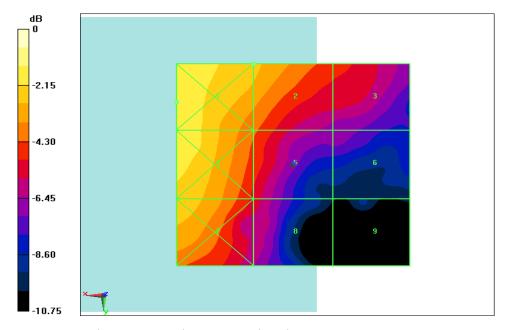
Reference Value = 10.55 V/m; Power Drift = -0.11 dB

Applied MIF = -1.46 dB

RF audio interference level = 21.20 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
22.26 dBV/m	21.2 dBV/m	19.2 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
22.12 dBV/m	19.67 dBV/m	17.08 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
21.52 dBV/m	18.58 dBV/m	14.63 dBV/m



0 dB = 15.47 V/m = 23.79 dBV/m

Fig B.20 HAC RF E-Field LTE Band41 64QAM 2549.5MHz



HAC RF E-Field LTE Band41 64QAM Low

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: LTE Band41; Frequency: 2506 MHz; Duty Cycle: 1:1.58

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

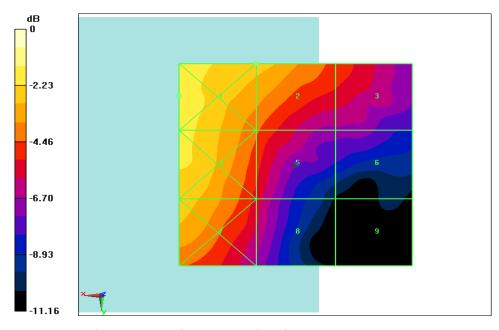
Reference Value = 10.61 V/m; Power Drift = -0.02 dB

Applied MIF = -1.56 dB

RF audio interference level = 20.97 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
21.96 dBV/m	20.97 dBV/m	18.98 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
21.87 dBV/m	19.36 dBV/m	16.78 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
21.1 dBV/m	18.19 dBV/m	13.81 dBV/m



0 dB = 15.24 V/m = 23.66 dBV/m

Fig B.21 HAC RF E-Field LTE Band41 64QAM Low



ANNEX C SYSTEM VALIDATION RESULT

E SCAN of Dipole 835 MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon r = 1$; $\rho = 1000$ kg/m3 Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 15mm/Hearing Aid Compatibility Test (41x361x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

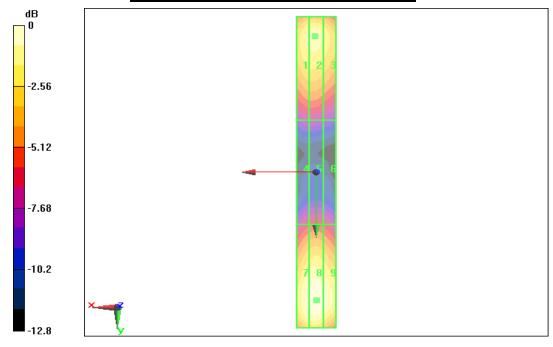
Reference Value = 106.9 V/m; Power Drift = -0.01 dB

Applied MIF = 0.00 dB

RF audio interference level = 40.53 dBV/m

Emission category: M3

	Grid 2M3 40.51 dBV/m	Grid 3 M3
		Grid 6 M4
35.93 dBV/m	36.04 dBV/m	35.88 dBV/m
Grid 7 M3	Grid 8 M3	Grid 9 M3
40.34 dBV/m	40.53 dBV/m	40.46 dBV/m



0 dB = 40.53 dBV/m



E SCAN of Dipole 1880 MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 154.9 V/m; Power Drift = 0.02 dB

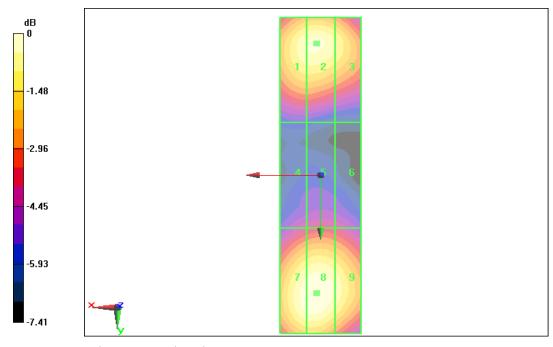
Applied MIF = 0.00 dB

RF audio interference level = 39.45 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1M2	Grid 2M2	Grid 3M2
39.21 dBV/m	39.45 dBV/m	39.36 dBV/m
Grid 4M2	Grid 5M2	Grid 6M2
37.22 dBV/m	37.36 dBV/m	37.26 dBV/m
Grid 7M2	Grid 8M2	Grid 9M2
38.78 dBV/m	39.05dBV/m	38.98 dBV/m



0 dB = 39.45 dBV/m



E SCAN of Dipole 2600 MHz

Date: 2018-4-29

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Communication System: CW; Frequency: 2600 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD2600 Dipole = 15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

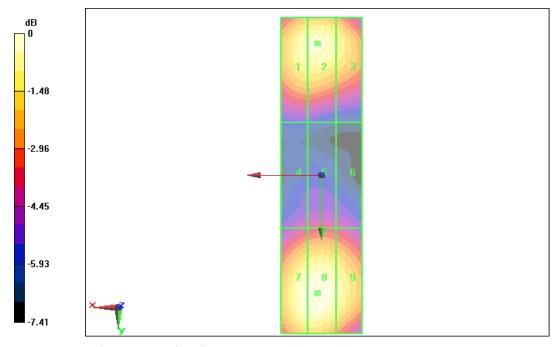
Reference Value = 59.87 V/m; Power Drift = 0.02 dB

Applied MIF = 0.00 dB

RF audio interference level = 38.69 dBV/m

Emission category: M2

Grid 1M2	Grid 2M2	Grid 3M2
38.21 dBV/m	38.45 dBV/m	38.36 dBV/m
Grid 4M2	Grid 5M2	Grid 6M2
38.22 dBV/m	38.36 dBV/m	38.69 dBV/m
Grid 7M2	Grid 8M2	Grid 9M2
38.58 dBV/m	38.05dBV/m	38.48 dBV/m



0 dB = 38.69 dBV/m



ANNEX D PROBE CALIBRATION CERTIFICATE

E_Probe ER3DV6

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Client

CTTL (Auden)

Certificate No: ER3-2272_Dec17

CALIBRATION CERTIFICATE

Object

ER3DV6 - SN:2272

Calibration procedure(s)

QA CAL-02.v8, QA CAL-25.v6

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

December 19, 2017

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-17 (No. 217-02521/02522)	Apr-18
Power sensor NRP-Z91	SN: 103244	04-Apr-17 (No. 217-02521)	Apr-18
Power sensor NRP-Z91	SN: 103245	04-Apr-17 (No. 217-02525)	Apr-18
Reference 20 dB Attenuator	SN: S5277 (20x)	07-Apr-17 (No. 217-02528)	Apr-18
Reference Probe ER3DV6	SN: 2328	10-Oct-17 (No. ER3-2328_Oct17)	Oct-18
DAE4	SN: 789	2-Aug-17 (No. DAE4-789_Aug17)	Aug-18
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-16)	In house check: Jun-18
Network Analyzer HP 8753E	SN: US37390585	18-Oct-01 (in house check Oct-17)	In house check: Oct-18

Calibrated by:

Name
Function
Signature

Laboratory Technician

Approved by:

Katja Pokovic
Technical Manager

Issued: December 20, 2017

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: ER3-2272_Dec17

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

Glossary:

NORMx,y,z

sensitivity in free space diode compression point

CF A, B, C, D

crest factor (1/duty_cycle) of the RF signal modulation dependent linearization parameters

Polarization φ

φ rotation around probe axis

Polarization 9

9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., $\vartheta = 0$ is normal to probe axis

Connector Angle

information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
- b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.0, November 2013

Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- NORM(f)x,y,z = NORMx,y,z * frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

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ER3DV6 - SN:2272

December 19, 2017

Probe ER3DV6

SN:2272

Manufactured: Calibrated: November 29, 2001 December 19, 2017

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

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ER3DV6 - SN:2272

December 19, 2017

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2272

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm $(\mu V/(V/m)^2)$	1.60	1.67	1.72	± 10.1 %
DCP (mV) ^B	101.0	97.8	100.7	

Modulation Calibration Parameters

UID	Communication System Name		A dB	B dB√μV	С	D dB	VR mV	Unc ^E (k=2)
0	CW	X	0.0	0.0	1.0	0.00	200.2	±3.5 %
		Y	0.0	0.0	1.0		165.8	
		Z	0.0	0.0	1.0		197.0	

Note: For details on UID parameters see Appendix.

Sensor Model Parameters

	C1 fF	C2 fF	α V-1	T1 ms.V ⁻²	T2 ms.V ⁻¹	T3 ms	T4 V ⁻²	T5 V ⁻¹	Т6
X	94.34	448.4	35.94	25.97	1.333	5.10	0.00	0.662	1.014
Υ	100.1	483.8	36.93	26.47	1.401	5.10	0.00	0.669	1.019
Z	83.01	396.9	36.42	29.84	3.892	5.10	0.00	0.874	1.016

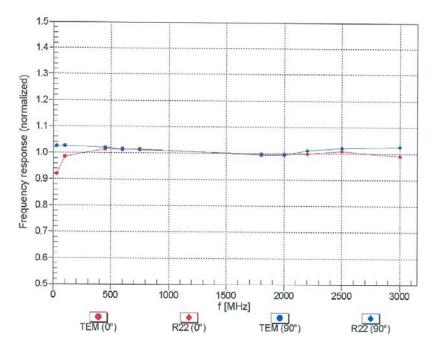
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

B Numerical linearization parameter: uncertainty not required.
E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the



ER3DV6 - SN:2272 December 19, 2017

Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

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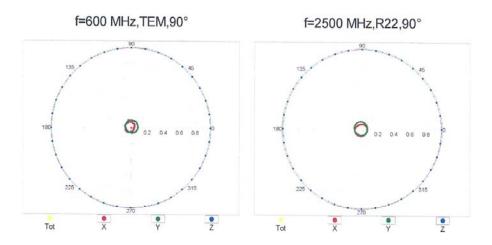


ER3DV6 - SN:2272 December 19, 2017

Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$

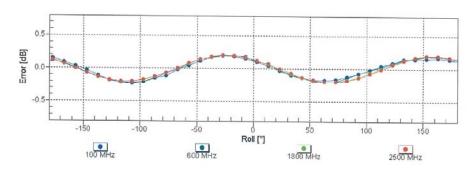


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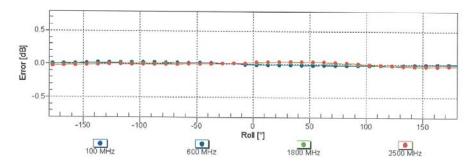
ER3DV6 – SN:2272 December 19, 2017

Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$

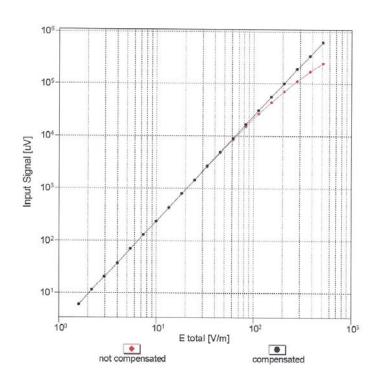


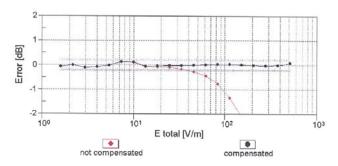
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)



ER3DV6 – SN:2272 December 19, 2017

Dynamic Range f(E-field) (TEM cell , f = 900 MHz)





Uncertainty of Linearity Assessment: ± 0.6% (k=2)

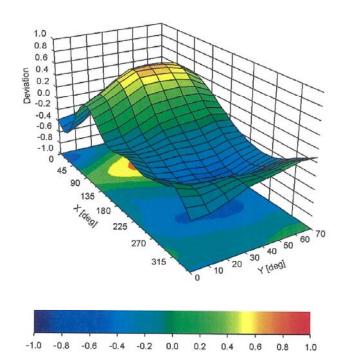
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ER3DV6 - SN:2272 December 19, 2017

Deviation from Isotropy in Air

Error (φ, θ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

Certificate No: ER3-2272_Dec17



ER3DV6 - SN:2272

December 19, 2017

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2272

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	112.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

Certificate No: ER3-2272_Dec17



ANNEX E DIPOLE CALIBRATION CERTIFICATE

Dipole 835 MHz

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accreditation No.: SCS 0108

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Client CTTI (Auden)

CD0051/0 1000 A....17

	CERTIFICATI		
Object	CD835V3 - SN: 1	1023	
Calibration procedure(s)	QA CAL-20.v6 Calibration proce	dure for dipoles in air	
Calibration date:	August 23, 2017		
		onal standards, which realize the physical unit robability are given on the following pages and	
		ry facility: environment temperature (22 ± 3)°C	
Calibration Equipment used (M&		, , ,	,, ,
Primary Standards	ID#	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-17 (No. 217-02521/02522)	Apr-18
Power sensor NRP-Z91	SN: 103244	04-Apr-17 (No. 217-02521)	Apr-18
	SN: 103245	04-Apr-17 (No. 217-02522)	Apr-18
Power sensor NRP-Z91			
	SN: 5058 (20k)	07-Apr-17 (No. 217-02528)	Apr-18
Reference 20 dB Attenuator	SN: 5058 (20k) SN: 5047.2 / 06327	07-Apr-17 (No. 217-02528) 07-Apr-17 (No. 217-02529)	Apr-18 Apr-18
Reference 20 dB Attenuator Type-N mismatch combination			Apr-18 Apr-18 Dec-17
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6	SN: 5047.2 / 06327	07-Apr-17 (No. 217-02529)	Apr-18
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6	SN: 5047.2 / 06327 SN: 2336	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16)	Apr-18 Dec-17
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards	SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16) 30-Dec-16 (No. H3-6065_Dec16) 13-Jul-17 (No. DAE4-781_Jul17) Check Date (in house)	Apr-18 Dec-17 Dec-17
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B	SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16) 30-Dec-16 (No. H3-6065_Dec16) 13-Jul-17 (No. DAE4-781_Jul17) Check Date (in house) 09-Oct-09 (in house check Sep-14)	Apr-18 Dec-17 Dec-17 Jul-18
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A	SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16) 30-Dec-16 (No. H3-6065_Dec16) 13-Jul-17 (No. DAE4-781_Jul17) Check Date (in house) 09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14)	Apr-18 Dec-17 Dec-17 Jul-18 Scheduled Check
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A	SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16) 30-Dec-16 (No. H3-6065_Dec16) 13-Jul-17 (No. DAE4-781_Jul17) Check Date (in house) 09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14) 09-Oct-09 (in house check Sep-14)	Apr-18 Dec-17 Dec-17 Jul-18 Scheduled Check In house check: Oct-17 In house check: Oct-17 In house check: Oct-17
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16) 30-Dec-16 (No. H3-6065_Dec16) 13-Jul-17 (No. DAE4-781_Jul17) Check Date (in house) 09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14) 09-Oct-09 (in house check Sep-14) 27-Aug-12 (in house check Oct-15)	Apr-18 Dec-17 Dec-17 Jul-18 Scheduled Check In house check: Oct-17 In house check: Oct-17 In house check: Oct-17 In house check: Oct-17
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A	SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16) 30-Dec-16 (No. H3-6065_Dec16) 13-Jul-17 (No. DAE4-781_Jul17) Check Date (in house) 09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14) 09-Oct-09 (in house check Sep-14)	Apr-18 Dec-17 Dec-17 Jul-18 Scheduled Check In house check: Oct-17 In house check: Oct-17 In house check: Oct-17
Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8753E	SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US37390585	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16) 30-Dec-16 (No. H3-6065_Dec16) 13-Jul-17 (No. DAE4-781_Jul17) Check Date (in house) 09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14) 27-Aug-12 (in house check Oct-15) 18-Oct-01 (in house check Oct-16) Function	Apr-18 Dec-17 Dec-17 Jul-18 Scheduled Check In house check: Oct-17 Signature
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US37390585	07-Apr-17 (No. 217-02529) 30-Dec-16 (No. ER3-2336_Dec16) 30-Dec-16 (No. H3-6065_Dec16) 13-Jul-17 (No. DAE4-781_Jul17) Check Date (in house) 09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14) 09-Oct-09 (in house check Sep-14) 27-Aug-12 (in house check Oct-15) 18-Oct-01 (in house check Oct-16)	Apr-18 Dec-17 Dec-17 Jul-18 Scheduled Check In house check: Oct-17

Certificate No: CD835V3-1023_Aug17

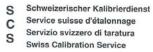




Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland







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References

- [1] ANSI-C63.19-2007 American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.
- [2] ANSI-C63.19-2011 American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 10 mm (15 mm for [2]) above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1] and [2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (15 mm for [2]) (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
 antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The
 maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as
 calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the
 feed point.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: CD835V3-1023_Aug17



Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.0
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	10, 15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 835 MHz

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW input power	0.457 A/m ± 8.2 % (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	168.6 V/m = 44.54 dBV/m
Maximum measured above low end	100 mW input power	165.9 V/m = 44.40 dBV/m
Averaged maximum above arm	100 mW input power	167.3 V/m ± 12.8 % (k=2)

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	108.0 V/m = 40.67 dBV/m
Maximum measured above low end	100 mW input power	107.9 V/m = 40.66 dBV/m
Averaged maximum above arm	100 mW input power	108.0 V/m ± 12.8 % (k=2)



Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	16.8 dB	41.0 Ω - 9.7 jΩ
835 MHz	23.2 dB	53.2 Ω + 6.4 jΩ
900 MHz	15.7 dB	52.8 Ω - 16.9 jΩ
950 MHz	23.1 dB	48.9 Ω + 6.9 jΩ
960 MHz	16.9 dB	58.6 Ω + 13.1 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

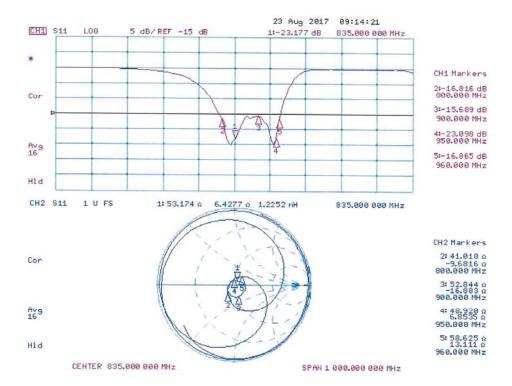
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.



Impedance Measurement Plot





DASY5 H-field Result

Test Laboratory: SPEAG Lab2

Date: 22.08.2017

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1023

Communication System: UID 0 - CW ; Frequency: 835 MHz Medium parameters used: σ = 0 S/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: H3DV6 SN6065; ; Calibrated: 30.12.2016
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 13.07.2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.0(1446); SEMCAD X 14.6.10(7417)

Dipole H-Field measurement @ 835MHz/H-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test

(41x361x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.4830 A/m; Power Drift = 0.04 dB

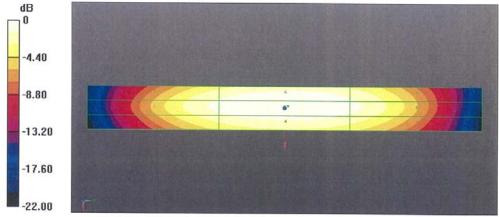
PMR not calibrated. PMF = 1.000 is applied.

H-field emissions = 0.4568 A/m

Near-field category: M4 (AWF 0 dB)

PMF scaled H-field

Grid 1 M4		
0.368 A/m	0.405 A/m	0.392 A/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
0.416 A/m	0.457 A/m	0.446 A/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
0.373 A/m	0.409 A/m	0.398 A/m



0 dB = 0.4568 A/m = -6.81 dBA/m

Certificate No: CD835V3-1023_Aug17



DASY5 E-field Result

Date: 22.08.2017

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1023

Communication System: UID 0 - CW ; Frequency: 835 MHz Medium parameters used: σ = 0 S/m, ϵ_r = 1; ρ = 1000 kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 30.12.2016;
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 13.07.2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.0(1446); SEMCAD X 14.6.10(7417)

$Dipole\ E\text{-Field measurement}\ @\ 835MHz/E\text{-Scan-835MHz}\ d\text{=}10mm/Hearing\ Aid\ Compatibility\ Test }$

(41x361x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 108.5 V/m; Power Drift = -0.03 dB

Applied MIF = 0.00 dB

RF audio interference level = 44.54 dBV/m

Emission category: M3

MIF scaled E-field

Grid 1 M3 44.17 dBV/m		Grid 3 M3 44.08 dBV/m
Grid 4 M4 38.83 dBV/m	STATE OF THE PARTY	Grid 6 M4 38.86 dBV/m
Grid 7 M3 44.02 dBV/m		Grid 9 M3 44.45 dBV/m

Certificate No: CD835V3-1023_Aug17



Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test

(41x361x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 108.0 V/m; Power Drift = 0.01 dB

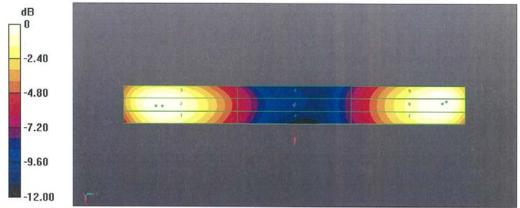
Applied MIF = 0.00 dB

RF audio interference level = 40.67 dBV/m

Emission category: M3

MIF scaled E-field

 	Grid 3 M3 40.47 dBV/m
The second secon	Grid 6 M4 36.03 dBV/m
 Grid 8 M3 40.67 dBV/m	Grid 9 M3 40.6 dBV/m



0 dB = 168.6 V/m = 44.54 dBV/m